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Total Number of Pages: 02

Course: B.Tech

Sub\_Code:

REC4D002/REE4C003/REI4D002/REL4C003

4<sup>th</sup> Semester Back Examination: 2024-25

SUBJECT: Power Electronics

BRANCH(S): AEIE, ECE, ETC, EEE, Electrical

Time: 3 Hours

Max Marks: 100

Q.Code: S518

**Answer Question No.1 (Part-1) which is compulsory, any eight from Part-II and any two from Part-III.**

**The figures in the right hand margin indicate marks.**

**Part-I**

**Q1 Answer the following questions: (2 x 10)**

- a) Find the rms value of half wave rectified symmetrical square wave current of 3 A.
- b) What is a secondary breakdown of BJT?
- c) Define latching and holding current as applicable to SCR.
- d) What is the need of driver circuit in power switches?
- e) List different types of voltage control and current control device?
- f) What are the difference between freewheeling diode and feedback diode?
- g) In a single phase full converter, what will be the firing angle if the output voltage has peak and average values of 325V and 133V respectively?
- h) Draw the load current waveform of single phase voltage source inverter with R-L load.
- i) What are the advantages of bipolar switching over unipolar switching in SPWM control strategy as applied to inverters?
- j) Write the applications of dc-dc converters.

**Part-II**

**Q2 Only Focused-Short Answer Type Questions- (Answer Any Eight out of Twelve) (6 x 8)**

- a) Explain the different turn-on methods of Thyristor.
- b) Describe the resistance firing circuit used for triggering SCRs. Is it possible to get a firing angle greater than 90° with resistance firing? Illustrate your answer with appropriate waveforms.
- c) Draw and explain the VI characteristics of SCR.
- d) Describe gate triggering of a thyristor. Does gate current has any effect on the forward breakdown voltage? Discuss
- e) For a step-down dc-dc converter dc source voltage is 230 V, load resistance of 10 Ω. For a duty cycle of 0.4, find the average and rms value of output voltage. Assume the switches are ideal.

- f) The single-phase full bridge inverter has a resistive load of  $R = 2.4 \Omega$  and the dc input voltage is  $V_s = 48$  V. Determine (I) the rms output voltage at the fundamental frequency (II) the output power (III) The average and peak currents of each transistor (IV) the THD (v) DF
- g) A resistive load of  $10 \Omega$  is connected through a half wave SCR circuit to 220 V, 50 Hz, single phase source. Calculate the power delivered to load for a firing angle of  $40^\circ$ .
- h) Draw the switching model for power BJT. Also explain the secondary breakdown of BJT.
- i) Draw the input and output voltage wave form of a full wave converter.
- j) Explain sinusoidal pulse modulation as used in PWM inverters.
- k) A single-phase half wave converter is operated from a 120 V, 60 Hz supply and the load resistance is  $R = 10 \Omega$ . if the average output voltage is 25 % of the maximum possible average output voltage, calculate (I) the delay angle (II) the rms and average output currents (III) the average and rms thyristor current
- l) Give a brief comparison between BJT, MOSFET, IGBT, and SCR.

### Part-III

#### Only Long Answer Type Questions (Answer Any Two out of Four)

**(16 x 2)**

<b>Q3</b>	What is an IGBT? Describe the working of an IGBT. Derive the approximate and exact equivalent circuit of IGBT from its structural details. Also, describe its output and transfer characteristics.	<b>(16)</b>
<b>Q4</b>	Draw the output voltage waveform of 3-phase full bridge thyristor rectifier for a firing angle of $45^\circ$ explaining the operation of the converter.	<b>(16)</b>
<b>Q5</b>	Explain $180^\circ$ conduction scheme of a three phase voltage source inverter with relevant circuit diagram and waveform.	<b>(16)</b>
<b>Q6</b>	Describe the principle of Boost converter operation. Derive an expression for its average output voltage.	<b>(16)</b>